HA13118

18 W BTL Audio Power Amplifier

HITACHI

Description

The HA13118 is power IC designed for component car stereo amplifiers. At 13.2 V to 4 load, this power IC provides an output power of 18W with 10% distortion.

It is easy to design as this IC employs internal each protection circuit and the new small package.

Features

- Small outline package, easy to mount
- Internal each protection circuits
  - Surge protection circuit
  - Thermal shut-down circuit
  - Ground fault protection circuit
  - Power supply fault protection circuit

Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Rating	Unit	Note
Operating supply voltage	V_{CC}	18	V	
DC supply voltage	V_{CC} (DC)	26	V	1
Peak supply voltage	V_{CC} (peak)	50	V	2
Output current	Io (peak)	4	A	
Power dissipation	P_T	15	W	
Thermal resistance	θj – c	3.5	°C/W	
Junction temperature	Tj	150	°C	
Operating temperature	Topr	–30 to +80	°C	
Storage temperature	Tstg	–55 to +125	°C	

Notes: 1. Value at t = 30 sec.
2. Value at width tw = 200 ms and rise time tr = 1 ms.

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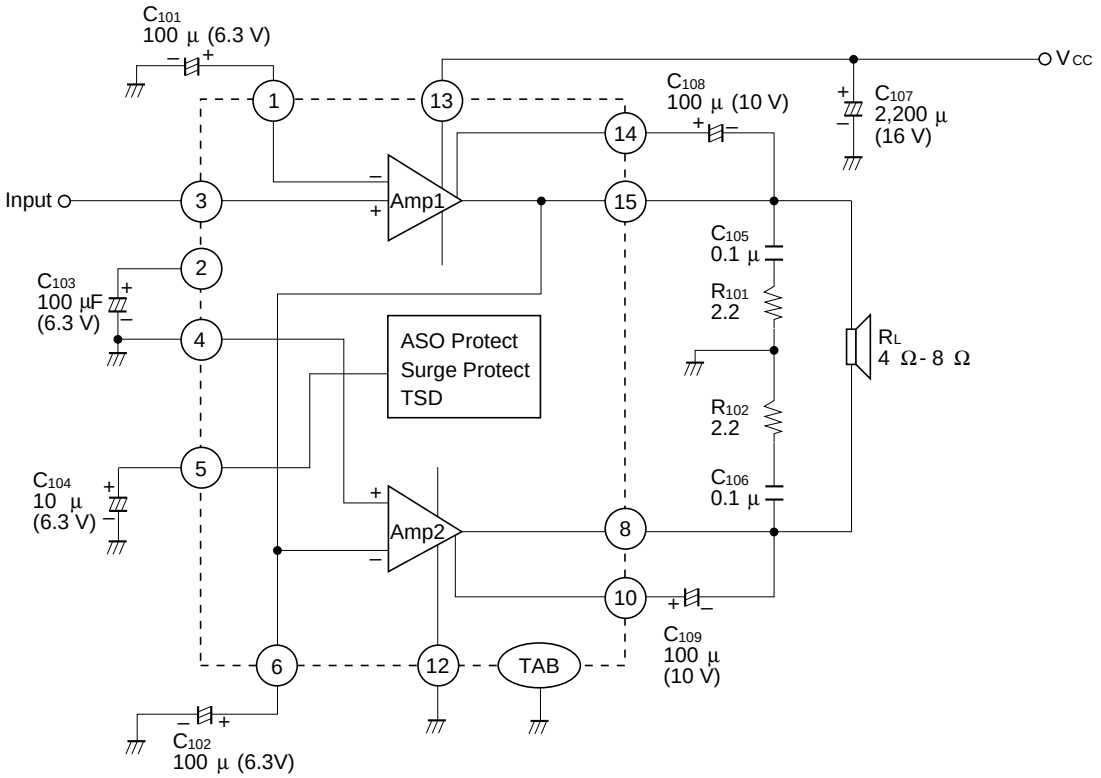
Electrical Characteristics (V_{CC} = 13.2 V, f = 1 kHz, R_L = 4 , Ta = 25 °C)

Item	Symbol	Min	Typ	Max	Unit	Test Conditions	
Quiescent current	I_Q	40	80	160	mA	Vin = 0	
Input bias voltage	V_B	—	20	40	mV	Vin = 0	
Output offset voltage	ΔV_Q	—	—	+330	mV	Vin = 0	
Voltage gain	G_V	53	55	57	dB	Vin = –55 dBm	
Output power	Pout	15	18	—	W	THD = 10 %	R_L = 4
		—	11	—			R_L = 8
Total harmonic distortion	THD	—	0.2	1.0	%	Pout = 1.5 W	
Output noise voltage	WBN	—	1.0	2.0	mV	Rg = 10 k , BW = 20 Hz 20 kHz	
Supply voltage rejection ratio	SVR	33	44	—	dB	f = 500 Hz	
Input resistance	Rin	20	30	40	k		
Rolloff frequency	f_L	—	20	—	Hz	ΔGv = –3 dB	Low
	f_H	10	20	40	kHz	from f = 1 kHz Ref.	High

Block Diagram



Note: C_{105}, C_{106} must be non secondary resonance type (non inductive) polyester film capacitor for keeping stability.

Figure 1 Typical Application Circuit

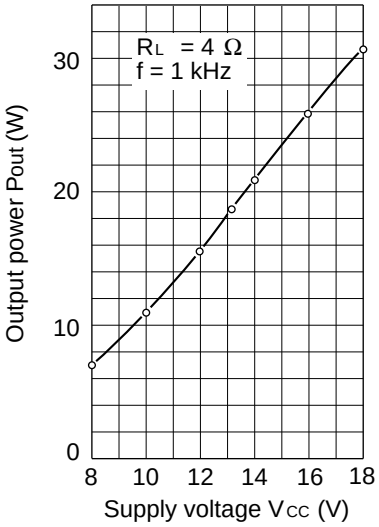


Figure 2 Output Power vs. Supply Voltage

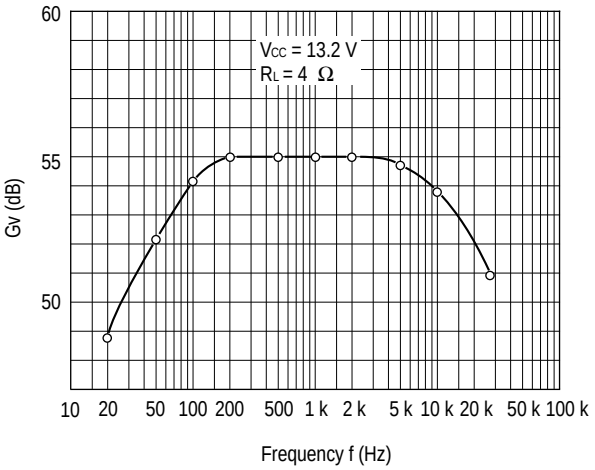


Figure 3 Voltage Gain vs. Frequency

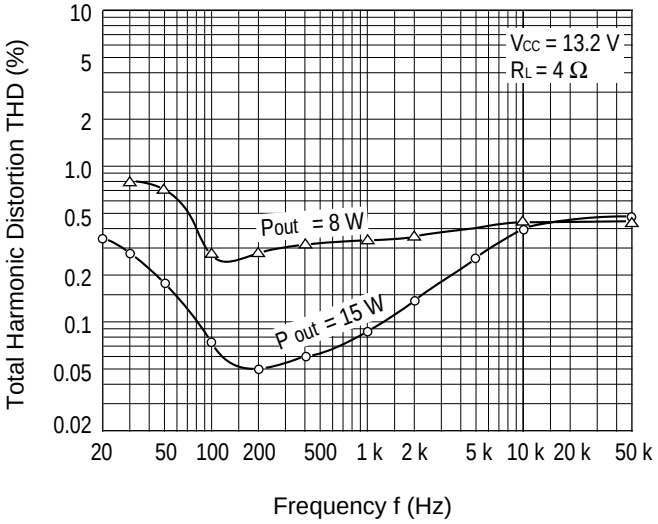


Figure 4 Total Harmonic Distortion vs. Frequency

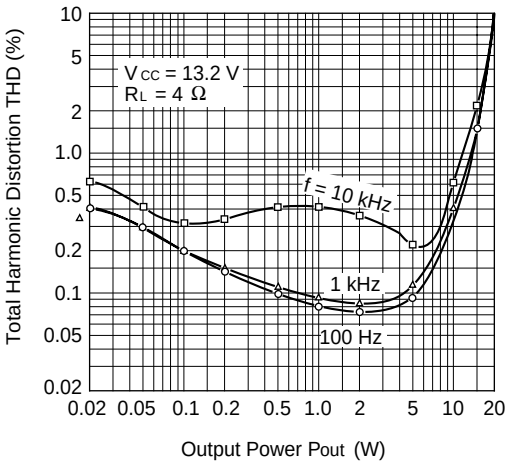


Figure 5 Total Harmonic Distortion vs. Output Power

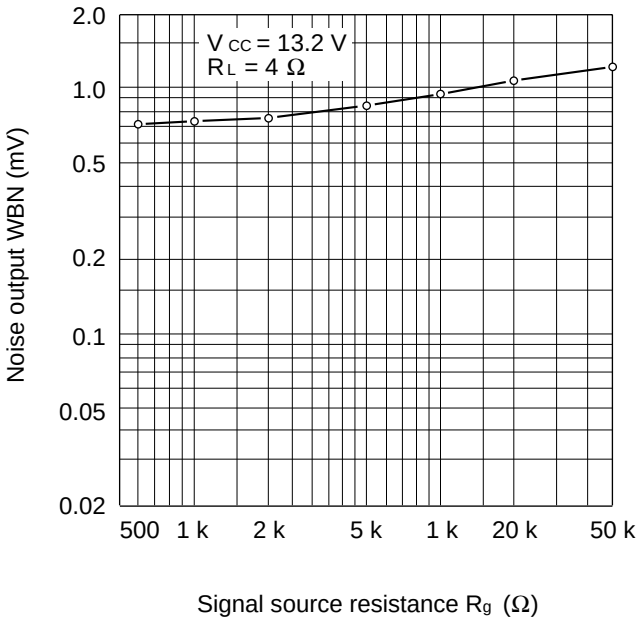


Figure 6 Noise Output vs. Signal Source Resistance

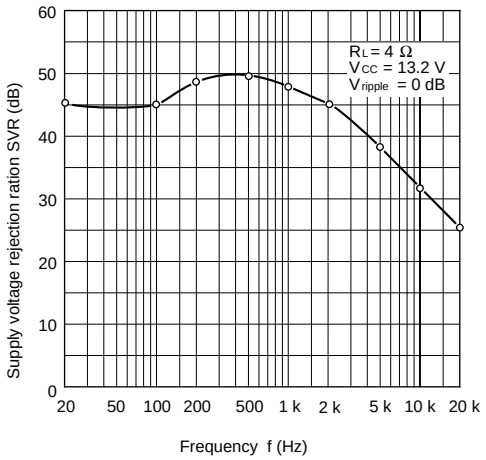
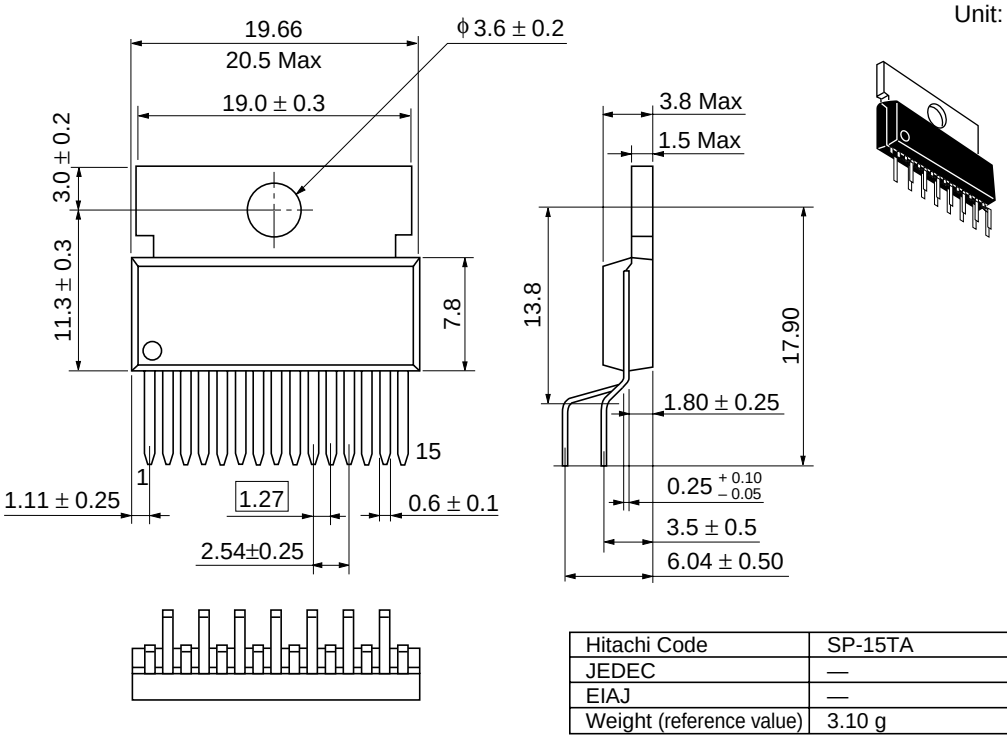


Figure 7 Supply Voltage Rejection Ratio vs. Frequency

Package Dimensions

Unit: mm



Hitachi Code	SP-15TA
JEDEC	—
EIAJ	—
Weight (reference value)	3.10 g

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